

UGC - Autonomous Institute
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UNIT-III

S.]	No	Questions	BT	CO	PO
Part-A(ShortAnswer Questions)					
-	1	Whatisbias?whatistheneedforbiasing	2	3	1
4	2	Whataretheconditionsforoperatingpoint?	3	3	1,2
	3	Drawasmallsignallowfrequencymodelofatransistor?	2	3	1,2
4		MentionimportantcharacteristicsofCEamplifier?	2	3	1,2,3
5		Write the typical values of transistor configuration in h-parameter model.	3	3	1,2
(6	Explain thermal stability?	2	3	1,2
7		Compare the three basing circuits	3	3	1,2
8		What is the need for biasing?	2	3	1,2
9		Explain, How to avoid the thermal runway?	2	3	1,2
10		Define the stability factor for Fixed bias circuit, collector to base bias, voltage divider bias circuit?	2	3	1,2
		Part-B(LongAnswerQuestions)			
11	a)	Drawthefixedbiascircuitandderivethestabilityfactor.	2	3	1
12	a)	DiscussthelowfrequencyresponseofBJTamplifierandtheeffect of coupling and bypass capacitors.	2	3	1,2
	b)	Whatistransistoramplifyingaction?	3	3	1,2
13		ExplainACandDCloadlineanalysisinBJT and discuss the criteria for fixing the Q- point.	2	3	1,2,3
14		Explain the h-parameter equivalent circuit for a typical common emitter amplifier and derive expression for Ai and Av.	2	3	1,2
15		What is the necessity of biasing circuits? Derive the expression for stability factor of a self bias circuit?	2	3	1,2
16		In a silicon transistor circuit with a fixed bias , VCC=9v,Rc=3K ohms Rb=8K ohms β =50 VBE=0.7V find the operating point and stability factor	2	3	1,2
17		Explain the need for biasing circuit? Describe about the factors affecting the operating point	2	3	1,2
18		Derive the stability factor for a fixed bias circuit	3	3	1,2
19		Derive the stability factor for a voltage divider bias circuit	3	3	1,2
20		Design the voltage divider circuit from the following Data $V_{cc} = 24V$, $\beta = 110$, $I_{cq} = 4mA$, $V_{ceq} = 8V$ and choose $V_E = V_{cc}/8$.	3	3	1,2